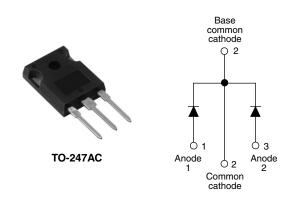
### Vishay High Power Products

# HEXFRED<sup>®</sup> Ultrafast Soft Recovery Diode, 2 x 6 A



SHA

| PRODUCT SUMMARY                              |          |  |  |  |
|--|----------|--|--|--|
| V <sub>R</sub>                               | 1200 V   |  |  |  |
| V <sub>F</sub> at 6 A at 25 °C               | 3.0 V    |  |  |  |
| I <sub>F(AV)</sub>                           | 2 x 6 A  |  |  |  |
| t <sub>rr</sub> (typical)                    | 26 ns    |  |  |  |
| T <sub>J</sub> (maximum)                     | 150 °C   |  |  |  |
| Q <sub>rr</sub> (typical)                    | 116 nC   |  |  |  |
| dI <sub>(rec)M</sub> /dt (typical) at 125 °C | 100 A/µs |  |  |  |
| I <sub>RRM</sub> (typical)                   | 4.4 A    |  |  |  |

### FEATURES

- Ultrafast recovery
- Ultrasoft recovery
- Very low I<sub>RRM</sub>
- Very low Q<sub>rr</sub>
- Specified at operating conditions
- Designed and qualified for industrial level

#### BENEFITS

- · Reduced RFI and EMI
- · Reduced power loss in diode and switching transistor
- Higher frequency operation
- Reduced snubbing
- Reduced parts count

#### DESCRIPTION

HFA12PA120C is a state of the art center tap ultrafast recovery diode. Employing the latest in epitaxial construction and advanced processing techniques it features a superb combination of characteristics which result in performance which is unsurpassed by any rectifier previously available. The HFA12PA120C has basic ratings of 1200 V and 6 A per leg continuous current. In addition to ultrafast recovery time, the HEXFRED® product line features extremely low values of peak recovery current ( $I_{\mbox{\scriptsize RRM}}$ ) and does not exhibit any tendency to "snap-off" during the tb portion of recovery. The HEXFRED features combine to offer designers a rectifier with lower noise and significantly lower switching losses in both the diode and the switching transistor. These HEXFRED advantages can help to significantly reduce snubbing, component count and heatsink sizes. The HEXFRED HFA12PA120C is ideally suited for applications in power supplies and power conversion systems (such as inverters, converters, UPS systems, and power factor correction circuits), motor drives, and many other similar applications where high speed, high efficiency is needed.

| ABSOLUTE MAXIMUM RATINGS                         |                                   |                         |               |       |  |
|--|-----------------------------------|-------------------------|---------------|-------|--|
| PARAMETER  | SYMBOL                            | TEST CONDITIONS         | VALUES        | UNITS |  |
| Cathode to anode voltage                         | V <sub>R</sub>                    |                         | 1200          | V     |  |
| Maximum continuous forward currentper leg        |                                   | T <sub>C</sub> = 100 °C | 6             |       |  |
| per device                                       |                                   |                         | 12            | А     |  |
| Single pulse forward current                     | I <sub>FSM</sub>                  |                         | 80            | A     |  |
| Maximum repetitive forward current               | I <sub>FRM</sub>                  |                         | 24            |       |  |
| Maximum power dissipation                        | D                                 | T <sub>C</sub> = 25 °C  | 62.5          | W     |  |
|  | P <sub>D</sub>                    | T <sub>C</sub> = 100 °C | 25            | vV    |  |
| Operating junction and storage temperature range | T <sub>J</sub> , T <sub>Stg</sub> |                         | - 55 to + 150 | °C    |  |

## HFA12PA120C



## Vishay High Power Products

### HEXFRED<sup>®</sup> Ultrafast Soft Recovery Diode, 2 x 6 A

| <b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C unless otherwise specified) |                 |  |      |      |      |       |  |
|--|-----------------|--|------|------|------|-------|--|
| PARAMETER  | SYMBOL          | TEST CONDITIONS                                      | MIN. | TYP. | MAX. | UNITS |  |
| Cathode to anode breakdown voltage   | $V_{BR}$        | I <sub>R</sub> = 100 μA                              |      | -    | -    |       |  |
| Maximum forward voltage V <sub>FM</sub>  |                 | I <sub>F</sub> = 6 A                                 | -    | 2.7  | 3.0  | v     |  |
|  | V <sub>FM</sub> | I <sub>F</sub> = 12 A                                | -    | 3.5  | 3.9  |       |  |
|  |                 | I <sub>F</sub> = 6 A, T <sub>J</sub> = 125 °C        | -    | 2.4  | 2.8  | ]     |  |
| Maximum reverse I <sub>RM</sub>  |                 | $V_R = V_R$ rated                                    | -    | 0.26 | 5.0  |       |  |
|  |                 | $T_J$ = 125 °C, $V_R$ = 0.8 x $V_R$ rated            | -    | 110  | 500  | μΑ    |  |
| Junction capacitance   | CT              | V <sub>R</sub> = 200 V                               | -    | 9.0  | 14   | pF    |  |
| Series inductance  | L <sub>S</sub>  | Measured lead to lead 5 mm from package body - 8.0 - |      | -    | nH   |       |  |

| <b>DYNAMIC RECOVERY CHARACTERISTICS</b> (T <sub>J</sub> = 25 °C unless otherwise specified) |                           |   |  |      |      |      |         |
|---|---------------------------|---|--|------|------|------|---------|
| PARAMETER   | SYMBOL                    | TEST CONDITIONS   |  | MIN. | TYP. | MAX. | UNITS   |
|   | t <sub>rr</sub>           | $I_F = 1.0 \text{ A}, \text{ d}I_F/\text{d}t = 200 \text{ A}/\mu\text{s}, \text{ V}_R = 30 \text{ V}$ |  | -    | 26   | -    |         |
| Reverse recovery time   | t <sub>rr1</sub>          | T <sub>J</sub> = 25 °C  | I <sub>F</sub> = 6 A<br>dI <sub>F</sub> /dt = 200 A/μs<br>V <sub>R</sub> = 200 V | -    | 53   | 80   | ns      |
|   | t <sub>rr2</sub>          | T <sub>J</sub> = 125 °C   |  | -    | 87   | 130  |         |
| Peak recovery current   | I <sub>RRM1</sub>         | T <sub>J</sub> = 25 °C  |  | -    | 4.4  | 8.0  | A<br>nC |
|   | I <sub>RRM2</sub>         | T <sub>J</sub> = 125 °C   |  | -    | 5.0  | 9.0  |         |
| Reverse recovery charge   | Q <sub>rr1</sub>          | T <sub>J</sub> = 25 °C  |  | -    | 116  | 320  |         |
|   | Q <sub>rr2</sub>          | T <sub>J</sub> = 125 °C   |  | -    | 233  | 585  |         |
| Peak rate of fall of recovery current during t <sub>b</sub>                                 | dl <sub>(rec)M</sub> /dt1 | T <sub>J</sub> = 25 °C  |  | -    | 180  | -    | A/µs    |
|   | dl <sub>(rec)M</sub> /dt2 | T <sub>J</sub> = 125 °C   |  | -    | 100  | -    | πµs     |

| THERMAL - MECHANICAL SPECIFICATIONS     |                   |  |              |      |            |                        |
|---|-------------------|--|--------------|------|------------|------------------------|
| PARAMETER                               | SYMBOL            | TEST CONDITIONS                            | MIN.         | TYP. | MAX.       | UNITS                  |
| Lead temperature                        | T <sub>lead</sub> | 0.063" from case (1.6 mm) for 10 s         | -            | -    | 300        | °C                     |
| Thermal resistance, junction to case    | R <sub>thJC</sub> |  | -            | -    | 2.0        |                        |
| Thermal resistance, junction to ambient | R <sub>thJA</sub> | thJA Typical socket mount -                |              | -    | 80         | K/W                    |
| Thermal resistance, case to heatsink    | R <sub>thCS</sub> | Mounting surface, flat, smooth and greased | -            | 0.50 | -          |                        |
| Waight                                  |                   |  | -            | 2.0  | -          | g                      |
| Weight                                  |                   | -  | 0.07         | -    | oz.        |                        |
| Mounting torque                         |                   |  | 6.0<br>(5.0) | -    | 12<br>(10) | kgf ⋅ cm<br>(lbf ⋅ in) |
| Marking device                          |                   | Case style TO-247AC (JEDEC)                | HFA12PA120C  |      | •          |                        |



### **HEXFRED<sup>®</sup>** Ultrafast Soft Recovery Diode, 2 x 6 A



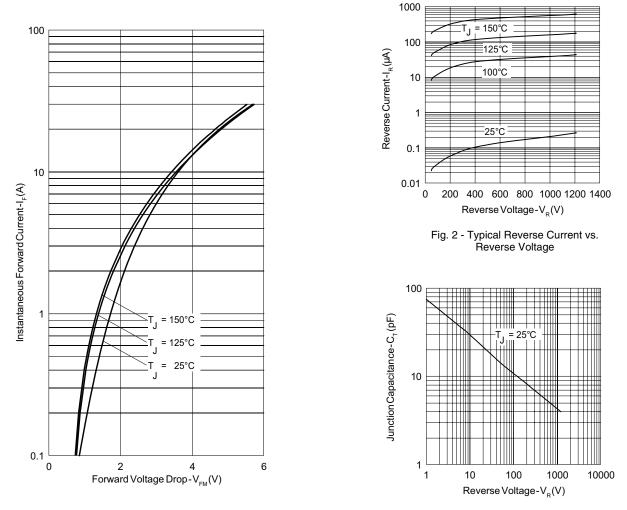
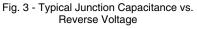


Fig. 1 - Maximum Forward Voltage Drop vs. Instantaneous Forward Current



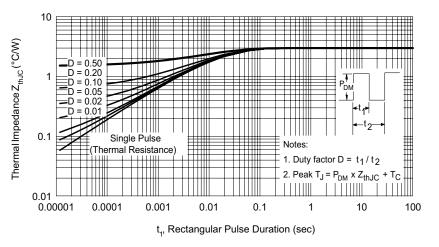


Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics

# HFA12PA120C

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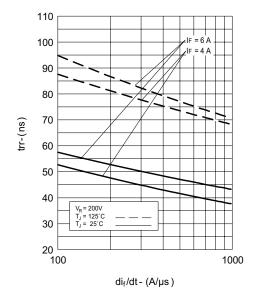
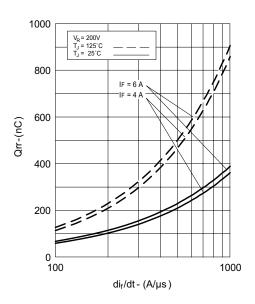


Fig. 5 - Typical Reverse Recovery Time vs.  $dI_F/dt$ 



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Fig. 7 - Typical Stored Charge vs.  $dI_F/dt$ 

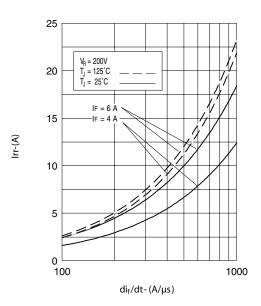
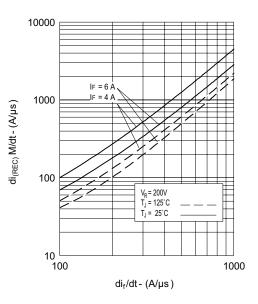
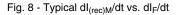


Fig. 6 - Typical Recovery Current vs. dl<sub>F</sub>/dt









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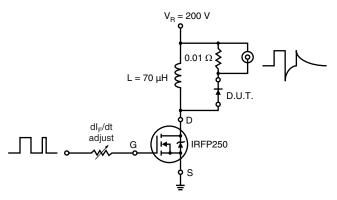


Fig. 9 - Reverse Recovery Parameter Test Circuit

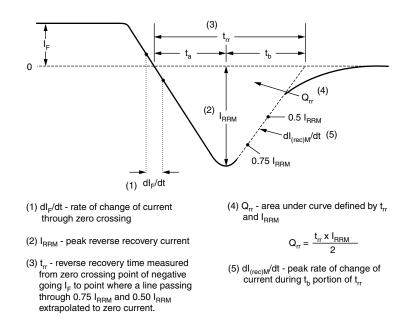


Fig. 10 - Reverse Recovery Waveform and Definitions

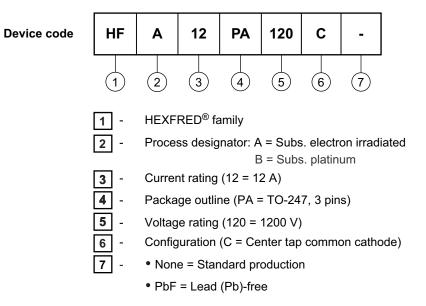
## HFA12PA120C



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### ORDERING INFORMATION TABLE



| LINKS TO RELATED DOCUMENTS                 |                                 |  |  |  |  |
|--|---------------------------------|--|--|--|--|
| Dimensions http://www.vishay.com/doc?95223 |                                 |  |  |  |  |
| Part marking information                   | http://www.vishay.com/doc?95226 |  |  |  |  |



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